NSN 5961-00-857-3355

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View Online at https://aerobasegroup.com/nsn/5961-00-857-3355 **Inclosure Material:** Metal **Overall Length:** 1.000 inches **Overall Diameter:** 0.435 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.438 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 120.0 collector to base voltage, dc and 120.0 collector to emitter voltage, dc and 6.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 3.00 amperes source cutoff current **Power Rating Per Characteristic:** 40.0 watts small-signal input power, common-collector absolute **Special Features:** Junction pattern arrangement: npn **Thread Series Designator: Terminal Type And Quantity:** 1 threaded stud and 2 tab, solder lug **Specification Data:** 80131-release3225 professional/industrial association specification Shelf Life: N/a **Unit Of Measure:**

Demilitarization: Yes - demil/mli

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